

# 1N914/A/B

## FEATURES :

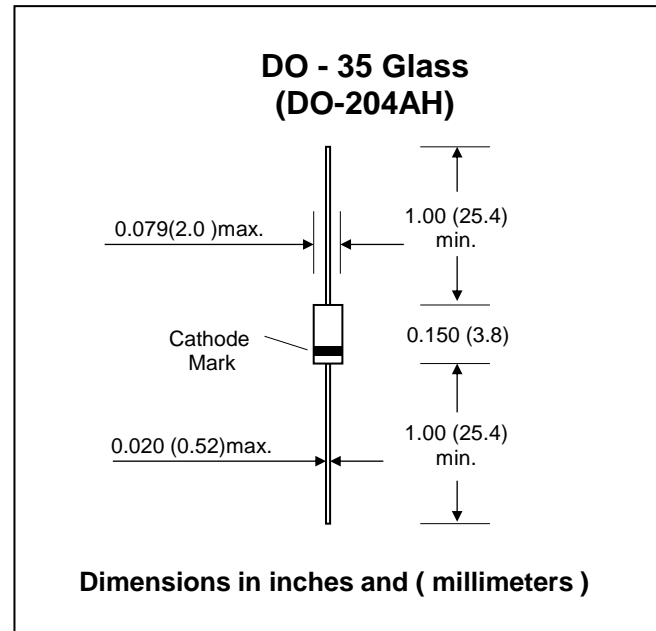
- High switching speed: max. 4 ns
- Continuous reverse voltage: max. 75 V
- Repetitive peak reverse voltage: max. 100 V
- Repetitive peak forward current: max. 225 mA
- Pb / RoHS Free

## MECHANICAL DATA :

Case: DO-35 Glass Case

Weight: approx. 0.13g

## HIGH SPEED SWITCHING DIODES



## Maximum Ratings and Thermal Characteristics (Rating at 25 °C ambient temperature unless otherwise specified.)

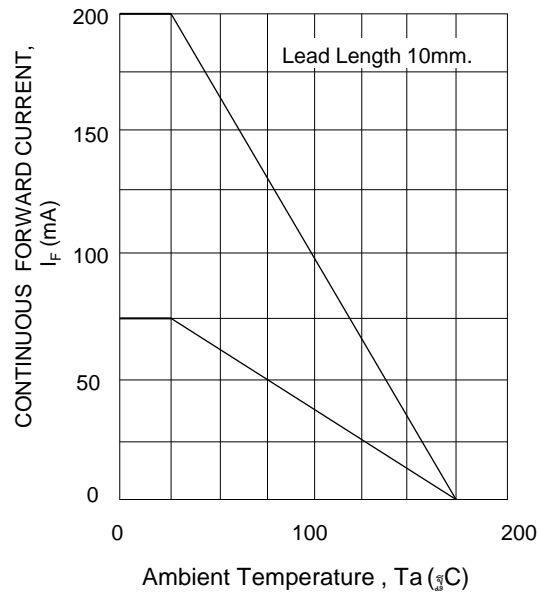
Parameter	Symbol	Value	Unit
Non-Repetitive Peak Reverse Voltage	$V_{RM}$	100	V
Reverse Voltage	$V_R$	75	V
Average Rectified Forward Current	$I_{F(AV)}$	75	mA
		200	
Forward Continuous Current	$I_{FM}$	150	mA
		300	
Non-repetitive Peak Forward Surge Current	$I_{FSM}$	1	A
		1	
		4	
Power Dissipation	$P_{tot}$	500	mW
Operating and Storage Temperature Range	$T_J, T_{stg}$	-65 to + 175	°C

## Electrical Characteristics ( $T_J = 25^\circ\text{C}$ unless otherwise noted)

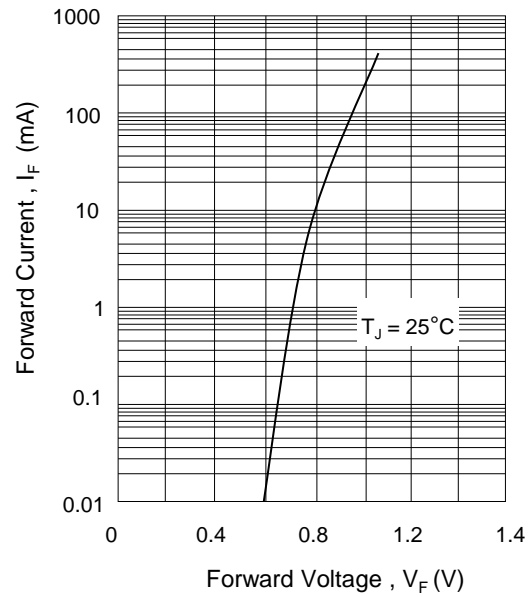
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Current	$I_R$	$V_R = 20\text{ V}$	-	-	25	nA
		$V_R = 75\text{ V}$	-	-	5	$\mu\text{A}$
		$V_R = 20\text{ V}, T_J = 150^\circ\text{C}$	-	-	50	$\mu\text{A}$
Forward Voltage	$V_F$	$I_F = 10\text{ mA}$	-	-	1.0	V
		$I_F = 20\text{ mA}$	-	-	1.0	V
		$I_F = 5\text{ mA}$	0.62	-	0.72	V
		$I_F = 100\text{ mA}$	-	-	1.0	V
Diode Capacitance	Cd	$f = 1\text{MHz}; V_R = 0$	-	-	4.0	pF
Reverse Recovery Time	$T_{rr}$	$I_F = 10\text{ mA to } I_R = 1\text{ mA}$ $V_R = 1\text{ mA}, R_L = 100\ \Omega$	-	-	4	ns

## RATING AND CHARACTERISTIC CURVES ( 1N914/A/B )

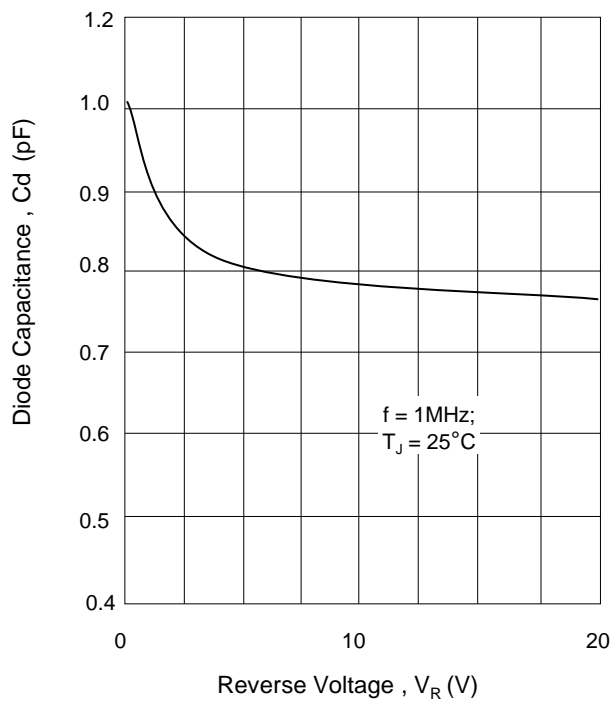
**FIG. 1 MAXIMUM PERMISSIBLE CONTINUOUS FORWARD CURRENT AS A FUNCTION OF AMBIENT TEMPERATURE.**



**FIG. 2 TYPICAL FORWARD VOLTAGE**



**FIG. 3 TYPICAL DIODE CAPACITANCE AS A FUNCTION OF REVERSE VOLTAGE**



**FIG. 4 TYPICAL REVERSE CURRENT VERSUS JUNCTION TEMPERATURE**

